



DMN10H170SVTQ

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
1001/	160mΩ @ V _{GS} = 10V	2.6A
100V	200mΩ @ V _{GS} = 4.5V	2.3A

Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$), yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- Power Management Functions
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.

100V N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

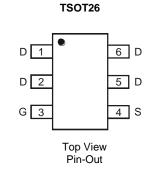
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

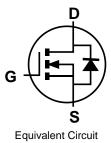
Mechanical Data

- Case: TSOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.015 grams (Approximate)



Top View





Ordering Information (Note 5)

Part Number	Case	Packaging
DMN10H170SVTQ-7	TSOT26	3,000/Tape & Reel
DMN10H170SVTQ-13	TSOT26	10,000/Tape & Reel

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

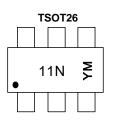
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



Marking Information



 $\begin{array}{l} 11N = Product \ Type \ Marking \ Code \\ YM = Date \ Code \ Marking \\ Y \ or \ \overline{Y} = Year \ (ex: \ C = 2015) \\ M = Month \ (ex: \ 9 = September) \end{array}$

Date Code Key

Year	2014		2015	2016		2017	2018		2019	2020		2021
Code	В		С	D		E	F		G	Н		
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	100	V
Gate-Source Voltage	V _{GSS}	±20	V
Continuous Drain Current (Note 7), V _{GS} = 10V	ID	2.6 2.1	A
Pulsed Drain Current (10µs Pulse, Duty Cycle ≦1%)	I _{DM}	11.2	A
Maximum Body Diode Continuous Current (Note 7)	Is	2.0	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit		
Total Dower Discinction	(Note 6)	Р	1.2	W	
Total Power Dissipation	(Note 7)	P _D	1.7		
Thermal Desistance, lunction to Ambient	(Note 6)	P	101		
Thermal Resistance, Junction to Ambient	(Note 7)	R _{0JA}	73	°C/W	
Thermal Resistance, Junction to Case	(Note 7)	R _{θJC}	15		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Notes: 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.



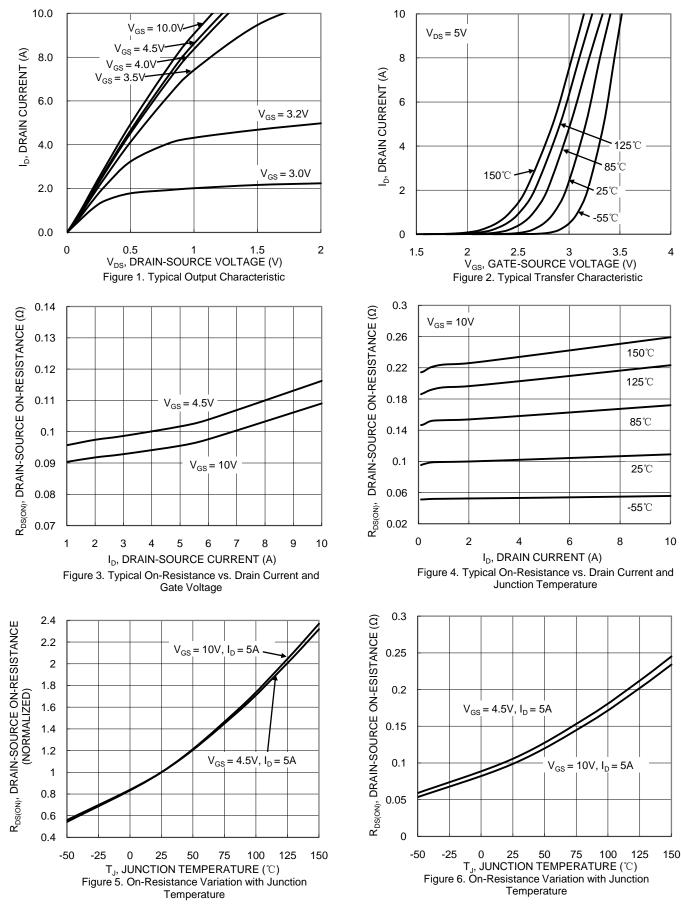
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						·
Drain-Source Breakdown Voltage	BV _{DSS}	100			V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	IDSS	_		1.0	μA	$V_{DS} = 100V, V_{GS} = 0V$
Gate-Body Leakage	Igss	_		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						·
Gate Threshold Voltage	V _{GS(TH)}	1.0	2.0	3.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance	5	_	115	160	mΩ	$V_{GS} = 10V, I_D = 5.0A$
Static Drain-Source On-Resistance	R _{DS(ON)}	_	124	200	mΩ	$V_{GS} = 4.5V, I_D = 5.0A$
Diode Forward Voltage	V _{SD}	_	0.9	1.0	V	$V_{GS} = 0V, I_{S} = 10A$
DYNAMIC CHARACTERISTICS (Note 9)	•		•	•		•
Input Capacitance	C _{iss}	_	1,167			$V_{DS} = 25V, V_{GS} = 0V,$ f = 1.0MHz
Output Capacitance	Coss	_	36	_	pF	
Reverse Transfer Capacitance	Crss	_	25	_		
Gate Resistance	Rg	_	1.3		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	4.9			
Total Gate Charge (V _{GS} = 10V)	Qg	_	9.7			
Gate-Source Charge	Q _{gs}	_	2.0		nC	$V_{DS} = 80V, I_D = 12.8A$
Gate-Drain Charge	Q _{gd}		2.0			
Turn-On Delay Time	t _{D(ON)}	_	10			
Turn-On Rise Time	t _R	_	11			$V_{DD} = 50V, V_{GS} = 10V,$
Turn-Off Delay Time	t _{D(OFF)}		42	_	ns	$R_g = 25\Omega, I_D = 12.8A$
Turn-Off Fall Time	t _F		12			
Reverse Recovery Time	t _{RR}	—	30		ns	
Reverse Recovery Charge	Q _{RR}		35		nC	V _{GS} = 0V, I _S =12.8A, di/dt=100A/µs

 8. Short duration pulse test used to minimize self-heating effect.
 9. Guaranteed by design. Not subject to product testing. Notes:



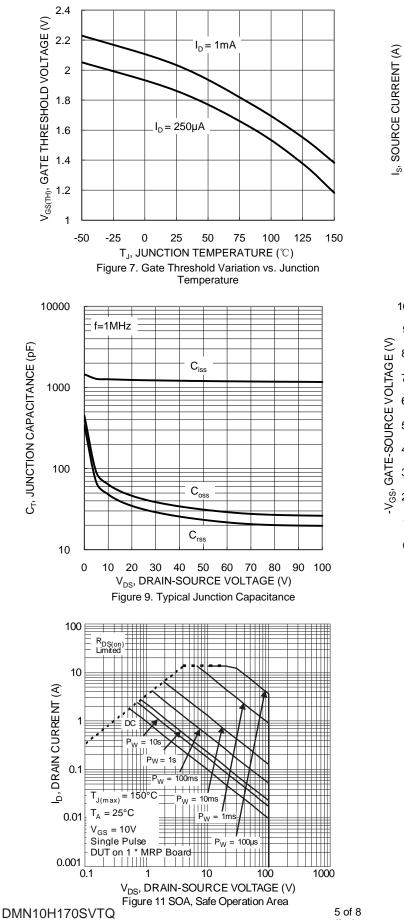
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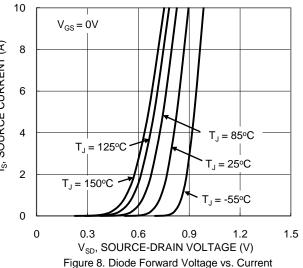


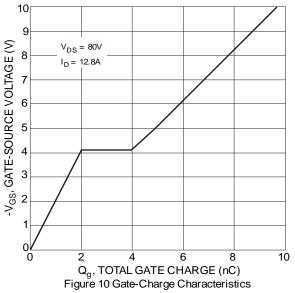
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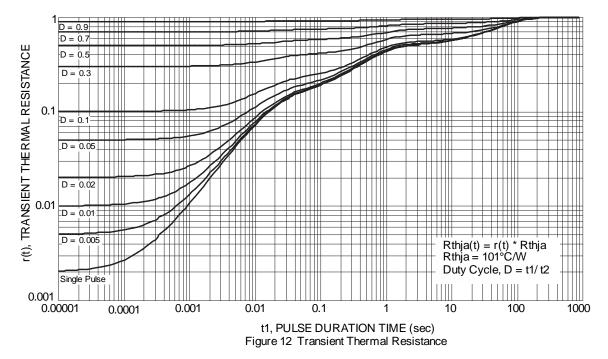


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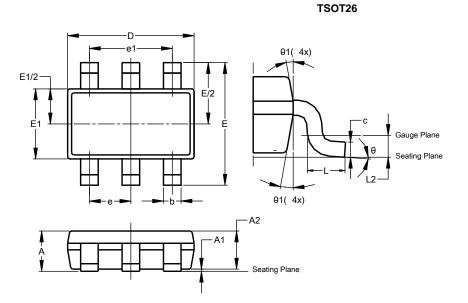






Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

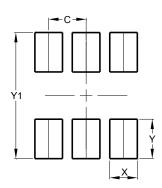


	TSOT26							
Dim	Min	Max	Тур					
Α	-	1.00	-					
A1	0.010	0.100	-					
A2	0.840	0.900	-					
D	2.800	3.000	2.900					
Е	2	.800 BS	С					
E1	1.500	1.700	1.600					
b	0.300	0.450	-					
С	0.120	0.200	-					
е	0.950 BSC							
e1	1	.900 BS	С					
L	0.30	0.50	-					
L2	0.250 BSC							
θ	0°	8°	4°					
θ1	4°	12°	-					
A	II Dimen	sions in	mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

TSOT26



Dimensions	Value (in mm)
С	0.950
Х	0.700
Y	1.000
Y1	3.199



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